MODIFIED PTO/SB/08 (08-00)

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	INFORMATIO	N DISCLO	SURE	Application Number	10/773,026			
STATEMENT BY APPLICANT				Filing Date	02/05/2004			
	Data Submitte	d: August 1	0 2004	First Named Inventor	Xiang			
Date Submitted: August 19, 2004				Group Art Unit	-2812 ag 13			
	(use as many st	neets as ne	cessary)	Examiner Name	Heather Doty			
Sheet	1	of	1	Attorney Docket Number	039153-0649			

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		U.S. Patent	Document		Date of Publication of	Pages, Columns, Lines, Where Relevant	
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NON PATENT LITERATURE DOCUMENTS								
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T [®]					
KO	A4	International Search Report for PCT/US2004/000982, 4 pages.						
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Examiner Signature	Heather Dorry	Date Considered	11/	16	105	
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*EXAMINER: Initial if reference considered, whether of oot citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document, 'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

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SERIAL NO. 10/773, 026 Form PTO-1449 U.S. DEPARTMENT OF COMMERCE ATTY, DOCKET NO. (MODIFIED) PATENT AND TRADEMARK OFFICE 039153-0649 **APPLICANT** INFORMATION DISCLOSURE CITATION Xiang et al. GROUP ART UNIT 2813 **FILING DATE** (Use several sheets if necessary) En:be determined **U.S. PATENT DOCUMENTS** FILING DATE **DOCUMENT EXAMINER** SUB-DATE NAME CLASS REF INITIAL CLASS NUMBER **APPROPRIATE A1** 4,683,645 08/04/87 Naguib et al. 437 41 4.745.082 05/17/88 Kwok 437 39 **A2** 4,784,718 11/15/88 Mitani et al. 156 643 **A3** 12/06/88 4,789,644 Meda 437 41 **A4** 05/30/89 Pfiester et al. 24 **A5** 4,835,112 437 4.954.867 09/04/90 Hosaka 357 52 Α6 02/26/91 Shirasaki 4.996,574 357 23.7 **A7 FOREIGN PATENT DOCUMENTS** TRANSLATION DOCUMENT SUB-DATE COUNTRY **CLASS** REF NUMBER **CLASS** YES NO 61-180466 8/13/86 Japan · X٠ A95 3-248433 11/06/91 Japan х A96 12/18/91 3-288471 Х Japan A97 A98 4-123439 4/23/92 Japan Х OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) Huang et al., Sub 50 nm FinFET: PMOS, , 1999 IEEE, 4 pages. A104 Yu et al., Ultra-Thin-Body Silicon-On-Insulator MOSFET's For Terabit-Scale Integration; date unknown, A105 pp. 623-626. Chatterjee et al., Sub-100nm Gate Length Metal Gate NMOS Transistors Fabricated by a Replacement Gate A106 Process; 1997 IEEE, 5 pages. Wolf et al., Silicon Processing for the VLSI Era Vol. 1: Process Technology, 1986, 15 pages. A107 Wolf, Silicon Processing for the VLSI Era Vol. 2: Process Integration, 9 pages. A108 **EXAMINER** DATE CONSIDERED EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include any copy of this form with next

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PATENT AND TRADEMARK OFFICE

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

ATTY. DOCKET NO.

039153-0649

APPLICANT

Xiang et al.

FILING DATE
To be determined

To be determined

To be determined

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ĺ.	A10	5,108,954	04/28/92	Sandhu et al.	437	200	
	A11	5,120,666	06/09/92	Gotou	437	40	
	A12	5,168,072	12/01/92	Moslehi	437	41	
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	A14	5,202,754	04/13/93	Bertin et al.	257	684	
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ATTY. DOCKET NO. 039153-0649 SERIAL NO. 10/773,02(

APPLICANT

INFORMATION DISCLOSURE CITATION

Xiang et al.

FILING DATE 25/04

GROUP ART UNIT 0813
To be determined

(Use several sheets if necessary)

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To be determined

INFORMATION DISCLOSURE CITATION

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